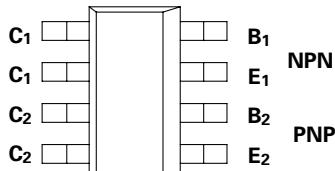


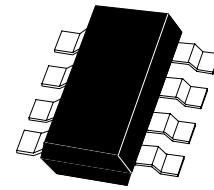
SM-8 COMPLEMENTARY MEDIUM POWER DARLINGTON TRANSISTORS

ISSUE 1 - NOVEMBER 1995

ZDT6705



PARTMARKING DETAIL – T6705



SM-8
(8 LEAD SOT223)

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	NPN	PNP	UNIT
Collector-Base Voltage	V_{CBO}	140	-140	V
Collector-Emitter Voltage	V_{CEO}	120	-120	V
Emitter-Base Voltage	V_{EBO}	10	-10	V
Peak Pulse Current	I_{CM}	4	-4	A
Continuous Collector Current	I_C	1	-1	A
Operating and Storage Temperature Range	T_j, T_{stg}	-55 to +150		°C

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
Total Power Dissipation at $T_{amb} = 25^\circ\text{C}^*$ Any single die "on" Both die "on" equally	P_{tot}	2.25 2.75	W W
Derate above 25°C^* Any single die "on" Both die "on" equally		18 22	mW/ °C mW/ °C
Thermal Resistance - Junction to Ambient* Any single die "on" Both die "on" equally		55.6 45.5	°C/ W °C/ W

* The power which can be dissipated assuming the device is mounted in a typical manner on a PCB with copper equal to 2 inches square.

ZDT6705

NPN TRANSISTOR ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	140			V	$I_C=100\mu A$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	120			V	$I_C=10mA^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	10			V	$I_E=100\mu A$
Collector Cutoff Current	I_{CBO}			0.01 10	μA	$V_{CB}=120V$ $V_{CB}=120V, T_{amb}=100^\circ C$
Emitter Cutoff Current	I_{EBO}			0.1	μA	$V_{EB}=8V$
Collector-Emitter Cutoff Current	I_{CES}			10	μA	$V_{CES}=120V$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			1.0 1.5	V	$I_C=250mA, I_B=0.25mA^*$ $I_C=1A, I_B=1mA^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$			1.8	V	$I_C=1A, I_B=1mA^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$			1.7	V	$I_C=1A, V_{CE}=5V^*$
Static Forward Current Transfer Ratio	h_{FE}	2K 5K 2K 0.5K		100K		$I_C=50mA, V_{CE}=5V$ $I_C=500mA, V_{CE}=5V^*$ $I_C=1A, V_{CE}=5V^*$ $I_C=2A, V_{CE}=5V^*$
Transition Frequency	f_T	150			MHz	$I_C=100mA, V_{CE}=10V$ $f=20MHz$
Input Capacitance	C_{ibo}		90		pF	$V_{EB}=500mV, f=1MHz$
Output Capacitance	C_{obo}		15		pF	$V_{CB}=10V, f=1MHz$
Switching Times	t_{on}		0.5		μs	$I_C=500mA, V_{CE}=10V$ $I_{B1}=I_{B2}=0.5mA$
	t_{off}		1.6		μs	

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$
For typical characteristics graphs see ZDT605 datasheet.

PNP TRANSISTOR
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-140			V	$I_C=-100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{CEO(SUS)}$	-120			V	$I_C=-10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-10			V	$I_E=-100\mu\text{A}$
Collector Cutoff Current	I_{CBO}			-0.1 -10	μA μA	$V_{CB}=-120\text{V}$ $V_{CB}=-120\text{V}$, $T_{amb}=100^{\circ}\text{C}$
Collector-Emitter Cutoff Current	I_{CES}			-10	μA	$V_{CES}=-80\text{V}$
Emitter Cutoff Current	I_{EBO}			-0.1	μA	$V_{EB}=-8\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$			-1.3 -2.5	V V	$I_C=-1\text{A}$, $I_B=-1\text{mA}^*$ $I_C=-2\text{A}$, $I_B=-2\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$			-1.8	V	$I_C=-1\text{A}$, $I_B=-10\text{mA}^*$
Base-Emitter Turn-On Voltage	$V_{BE(on)}$			-1.7	V	$I_C=-1\text{A}$, $V_{CE}=-5\text{V}^*$
Static Forward Current Transfer Ratio	h_{FE}	3K 3K 3K 2K		30K		$I_C=-10\text{mA}$, $V_{CE}=-5\text{V}^*$ $I_C=-100\text{mA}$, $V_{CE}=-5\text{V}^*$ $I_C=-1\text{A}$, $V_{CE}=-5\text{V}^*$ $I_C=-2\text{A}$, $V_{CE}=-5\text{V}^*$
Transition Frequency	f_T		160		MHz	$I_C=-100\text{mA}$, $V_{CE}=-10\text{V}$ $f=20\text{MHz}$
Input Capacitance	C_{ibo}		90		pF	$V_{EB}=-0.5\text{V}$, $f=1\text{MHz}$
Output Capacitance	C_{obo}		15		pF	$V_{CE}=-10\text{V}$, $f=1\text{MHz}$
Switching Times	t_{on}		0.6		μs	$I_C=-0.5\text{A}$, $V_{CE}=-10\text{V}$ $I_{B1}=I_{B2}=-0.5\text{mA}$
	t_{off}		0.8		μs	

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle $\leq 2\%$
 For typical characteristics graphs see ZDT705 datasheet.